

ML12009 ML12011 MECL PLL Components Dual Modulus Prescaler

Legacy Device: Motorola MC12009, MC12011

These devices are two-modulus prescalers which will divide by 5 and 6, 8 and 9, respectively. A MECL-to-MTTL translator is provided to interface directly with the Motorola MC12014 Counter Control Logic. In addition, there is a buffered clock input and MECL bias voltage source.

- ML12009 480 MHz (÷5/6), ML12011 550 MHz (÷8/9)
- MECL to MTTL Translator on Chip
- MECL and MTTL Enable Inputs
- 5.0 or -5.2 V Operation*
- Buffered Clock Input Series Input RC Typ, 20 Ω and 4.0 pF
- VBB Reference Voltage
- 310 mW (Typ)

* When using a 5.0 V supply, apply 5.0 V to Pin 1 (V_{CCO}), Pin 6 (MTTL V_{CC}), Pin 16 (V_{CC}), and ground Pin 8 (V_{EE}). When using -5.2 V supply, ground Pin 1 (V_{CCO}), Pin 6 (MTTL V_{CC}), and Pin 16 (V_{CC}) and apply -5.2 V to Pin 8 (V_{EE}). If the translator is not required, Pin 6 may be left open to conserve DC power drain.

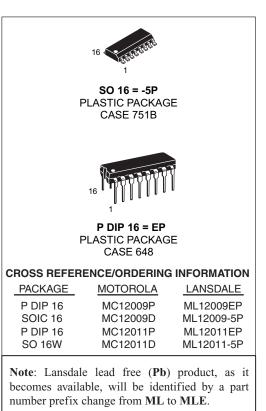
MAXIMUM RATINGS

Characteristic	Symbol	Rating	Unit
(Ratings above which device life ma	ay be impaired	(t	
Power Supply Voltage (V _{CC} = 0)	V _{EE}	-8.0	Vdc
Input Voltage (V _{CC} = 0)	V _{in}	0 to V _{EE}	Vdc
Output Source Current Continuous Surge	lO	<50 <100	mAdc
Storage Temperature Range	T _{stg}	-65 to 175	°C
(Peacempended Maximum Patinga	ahaya which	oorformonoo ma	w ha

(Recommended Maximum Ratings above which performance may be degraded)

Operating Temperature Range ML12009, ML12011	Т _А	-30 to 85	°C
DC Fan–Out (Note 1) (Gates and Flip–Flops)	n	70	—

NOTES: 1. AC fan-out is limited by desired system performance.



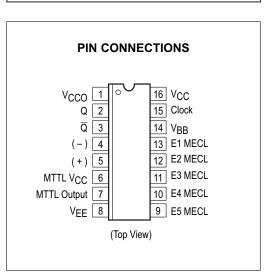


Figure 1. Logic Diagrams

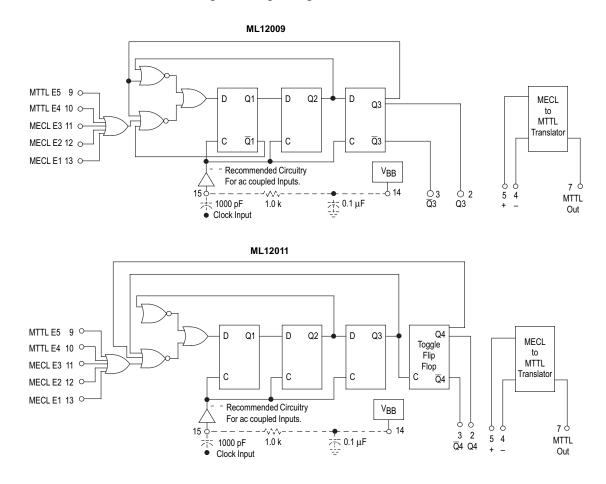


Figure 2. Typical Frequency Synthesizer Application

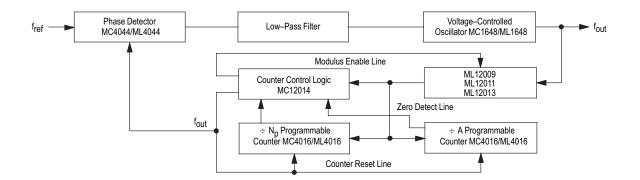


Figure 2b Generic block diagram showing prescaler connection to PLL Device

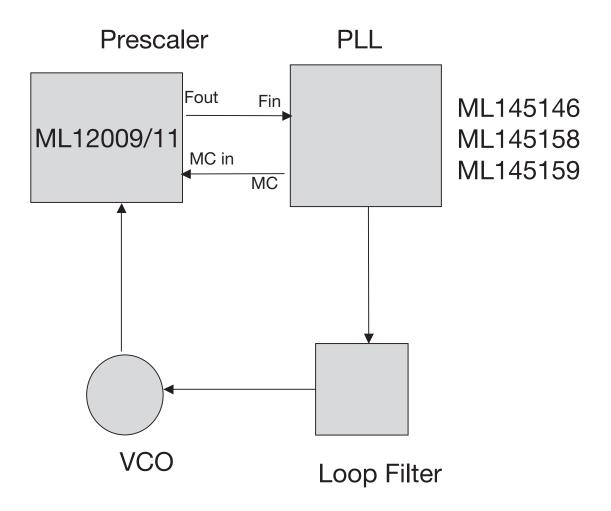


Figure 2b shows a generic block diagram of connecting a prescaler to a PLL device that supports dual modulus controls. Applicataion not AN535 describes using a two–modulus prescaler technique. By using prescaler higher frequencies can be achieved than by a single CMOS PLL device.

ELECTRICAL CHARACTERISTICS (Supply Voltage = -5.2 V, unless otherwise noted.)

					Test L	imits			
		Pin Under	-30	D∘C	25	°C	85	o°C]
Characteristic	Symbol	Test	Min	Max	Min	Max	Min	Max	Unit
Power Supply Drain Current	ICC1	8	-88		-80		-80		mAdc
	ICC2	6		5.2		5.2		5.2	mAdc
Input Current	linH1	15 11 12 13		375 375 375 375		250 250 250 250		250 250 250 250	μAdc
	linH2	4 5	1.7 1.7	6.0 6.0	2.0 2.0	6.0 6.0	2.0 2.0	6.4 6.4	mAdc
	l _{inH3}	5	0.7	3.0	1.0	3.0	1.0	3.6	
	linH4	9 10		100 100		100 100		100 100	μAdc
Leakage Current	linL1	15 11 12 13	-10 -10 -10 -10		-10 -10 -10 -10		-10 -10 -10 -10		µAdc
	linL2	9 10	-1.6 -1.6		-1.6 -1.6		-1.6 -1.6		mAdc
Reference Voltage	V _{BB}	14			-1.360	-1.160			Vdc
Logic '1' Output Voltage	VOH1 (Note 1)	2 3	-1.100 -1.100	-0.890 -0.890	-1.000 -1.000	-0.810 -0.810	-0.930 -0.930	-0.700 -0.700	Vdc
	V _{OH2}	7	-2.8		-2.6		-2.4]
Logic '0' Output Voltage	VOL1 (Note 1)	2 3	-1.990 -1.990	-1.675 -1.675	-1.950 -1.950	-1.650 -1.650	-1.925 -1.925	-1.615 -1.615	Vdc
	V _{OL2}	7		-4.26		-4.40		-4.48	1
Logic '1' Threshold Voltage	V _{OHA} (Note 2)	2 3	-1.120 -1.120		-1.020 -1.020		-0.950 -0.950		Vdc
Logic '0' Threshold Voltage	V _{OLA} (Note 3)	2 3		-1.655 -1.655		-1.630 -1.630		-1.595 -1.595	Vdc
Short Circuit Current	IOS	7	-65	-20	-65	-20	-65	-20	mAdc

ground voltages must be maintained between tests. The clock input is the waveform shown. 2. In addition to meeting the output levels specified, the device must divide by 5 or 8 during this test. The clock

VIHmax

VILmin

input is the waveform shown.

3. In addition to meeting the output levels specified, the device must divide by 6 or 9 during this test. The clock input is the waveform shown.

Each MECL 10,000 series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50 Ω resistor to -2.0 V. Test procedures are shown for only one gate. The other gates are tested in the same manner.

	•	, , , , ,		TEST V			UES		
					Volt				
	@ Test Temp	perature	V _{IHmax}	V _{ILmin}	V _{IHAmin}	V _{ILAmax}	VIH	VILH	
		–30°C	-0.890	-1.990	-1.205	-1.500	-2.8	-4.7	
		25°C	-0.810	-1.950	-1.105	-1.475	-2.8	-4.7	
		85°C	-0.700	-1.925	-1.035	-1.440	-2.8	-4.7	
		Pin	TE	ST VOLTAGE	APPLIED	TO PINS LIS	TED BELC	w	
Characteristic	Symbol	Under Test	V _{IHmax}	V _{ILmin}	VIHAmin	VILAmax	VIH	VIL	Gnd
Power Supply Drain Current	ICC1	8							1,16
	ICC2	6	4	5					6
Input Current	linH1	15 11 12 13	15 11 12 13						1,16 1,16 1,16 1,16
	linH2	4 5	5 5	4 4					6 6
	l _{inH3}	5	4	5					6
	linH4	9 10					9 10		1,16 1,16
Leakage Current	linL1	15 11 12 13							1,16 1,16 1,16 1,16 1,16
	linL2	9 10						9 10	1,16 1,16
Reference Voltage	V _{BB}	14							1,16
Logic '1' Output Voltage	V _{OH1} (Note 1)	2 3		11,12,13 11,12,13				9,10 9,10	1,16 1,16
	V _{OH2}	7	5	4					6
Logic '0' Output Voltage	VOL1 (Note 1)	2 3		11,12,13 11,12,13				9,10 9,10	1,16 1,16
	V _{OL2}	7	4	5					6
Logic '1' Threshold Voltage	V _{OHA} (Note 2)	2 3			11,12,13 11,12,13				1,16 1,16
Logic '0' Threshold Voltage	VOLA (Note 3)	2 3				11,12,13 11,12,13			1,16 1,16
Short Circuit Current	IOS	7	5	4				7	6

ELECTRICAL CHARACTERISTICS (continued) (Supply Voltage = -5.2 V, unless otherwise noted.)

NOTES: 1. Test outputs of the device must be tested by sequencing through the truth table. All input, power supply and ground voltages must be maintained between tests. The clock input is the waveform shown. 2. In addition to meeting the output levels specified, the device must divide by 5 or 8 during this test. The clock

input is the waveform shown.

Clock Input VIHmax VILmin

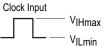
3. In addition to meeting the output levels specified, the device must divide by 6 or 9 during this test. The clock input is the waveform shown.

				TEST V	OLTAGE/CU	JRRENT VA	LUES				
				Volts			mA		1		
	@ Test Temp	Test Temperature VIHT VILT VEE				١L	ЮН]			
		–30°C	-3.2	-4.4	-5.2	-0.25	16	-0.40	1		
		25°C	-3.2	-4.4	-5.2	-0.25	16	-0.40]		
		85°C	-3.2	-4.4	-5.2	-0.25	16	-0.40]		
		Pin	TEST VOLTAGE APPLIED TO PINS LISTED BELOW								
Characteristic	Symbol	Under Test	VIHT	VILT	VEE	١L	IOL	Іон	Gnd		
Power Supply Drain Current	ICC1	8			8				1,16		
	ICC2	6			8				6		
Input Current	linH1	15 11 12 13	9,10 9,10 9,10		8 8 8 8				1,16 1,16 1,16 1,16 1,16		
	linH2	4 5			8 8				6 6		
	l _{inH3}	5			8				6		
	linH4	9 10			8 8				1,16 1,16		
Leakage Current	linL1	15 11 12 13			8,15 8,11 8,12 8,13				1,16 1,16 1,16 1,16 1,16		
	linL2	9 10			8 8				1,16 1,16		
Reference Voltage	V _{BB}	14			8	14			1,16		
Logic '1' Output Voltage	VOH1 (Note 1)	2 3			8 8				1,16 1,16		
	VOH2	7			8			7	6		
Logic '0' Output Voltage	VOL1 (Note 1)	2 3			8 8				1,16 1,16		
	V _{OL2}	7			8		7		6		
Logic '1' Threshold Voltage	VOHA (Note 2)	2 3	9,10 9,10		8 8				1,16 1,16		
Logic '0' Threshold Voltage	V _{OLA} (Note 2)	2 3		9,10 9,10	8 8				1,16 1,16		
Short Circuit Current	los	7			8				6		
				•							

ELECTRICAL CHARACTERISTICS (continued) (Supply Voltage = -5.2 V, unless otherwise noted.)

NOTES: 1. Test outputs of the device must be tested by sequencing through the truth table. All input, power supply and ground voltages must be maintained between tests. The clock input is the waveform shown. 2. In addition to meeting the output levels specified, the device must divide by 5 or 8 during this test. The clock

input is the waveform shown.



3. In addition to meeting the output levels specified, the device must divide by 6 or 9 during this test. The clock input is the waveform shown.

ELECTRICAL CHARACTERISTICS (Supply Voltage = 5.0 V, unless otherwise noted.)

					Test I	.imits			
		Pin Under	-30	0°C	25	°C	85	°C	1
Characteristic	Symbol	Test	Min	Max	Min	Max	Min	Мах	Unit
Power Supply Drain Current	ICC1	8	-88		-80		-80		mAdc
	I _{CC2}	6		5.2		5.2		5.2	mAdc
Input Current	linH1	15 11 12 13		375 375 375 375 375		250 250 250 250		250 250 250 250	μAdc
	linH2	4 5	1.7 1.7	6.0 6.0	2.0 2.0	6.0 6.0	2.0 2.0	6.4 6.4	mAdc
	l _{inH3}	5	0.7	3.0	1.0	3.0	1.0	3.6	
	linH4	9 10			100 100	100 100		100 100	μAdc
Leakage Current	linL1	15 11 12 13	-10 -10 -10 -10		-10 -10 -10 -10		-10 -10 -10 -10		μAdc
	linL2	9 10	-1.6 -1.6		-1.6 -1.6		-1.6 -1.6		mAdc
Reference Voltage	V _{BB}	14			3.67	3.87			Vdc
Logic '1' Output Voltage	VOH1 (Note 1)	2 3	3.900 3.900	4.110 4.110	4.000 4.000	4.190 4.190	4.070 4.070	4.300 4.300	Vdc
	VOH2	7	2.4		2.6		2.8		1
Logic '0' Output Voltage	V _{OL1} (Note 1)	2 3	3.070 3.070	3.385 3.385	3.110 3.110	3.410 3.410	3.135 3.135	3.445 3.445	Vdc
	V _{OL2}	7		0.94		0.80		0.72	1
Logic '1' Threshold Voltage	V _{OHA} (Note 2)	2 3	3.880 3.880		3.980 3.980		4.050 4.050		Vdc
Logic '0' Threshold Voltage	V _{OLA} (Note 3)	2 3		3.405 3.405		3.430 3.430		3.465 3.465	Vdc
Short Circuit Current	I _{OS}	7	-65	-20	-65	-20	-65	-20	mAdc

ground voltages must be maintained tested by sequencing an object in the during and between tests. The clock input is the waveform shown. 2. In addition to meeting the output levels specified, the device must divide by 5 or 8 during this test. The clock

VIHmax

VILmin

input is the waveform shown.

3. In addition to meeting the output levels specified, the device must divide by 6 or 9 during this test. The clock input is the waveform shown.

Each MECL 10,000 series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50 Ω resistor to -2.0 V. Test procedures are shown for only one gate. The other gates are tested in the same manner.

				TEST V	OLTAGE/CU	JRRENT VAL	UES		
					Volt	s]
	@ Test Temp	erature	VIHmax	VILmin	VIHAmin	V _{ILAmax}	VIH	VILH]
		−30°C	4.110	3.070	3.795	3.500	2.4	0.5]
		25°C	4.190	3.110	3.895	3.525	2.4	0.5]
		85°C	4.300	3.135	3.965	3.560	2.4	0.5	1
		Pin	TE	ST VOLTAGE	APPLIED	TO PINS LIS	TED BEL	w]
Characteristic	Symbol	Under Test	V _{IHmax}	V _{ILmin}	V _{IHAmin}	V _{ILAmax}	VIH	VIL	(V _{EE}) Gnd
Power Supply Drain Current	ICC1	8							8
	ICC2	6	4	5					8
Input Current	linH1	15 11 12 13	15 11 12 13						8 8 8 8
	linH2	4 5	5 5	4 4					8 8
	l _{inH3}	5	4	5					8
	linH4	9 10					9 10		8 8
Leakage Current	linL1	15 11 12 13							8,15 8,11 8,12 8,13
	linL2	9 10						9 10	8 8
Reference Voltage	V _{BB}	14							8
Logic '1' Output Voltage	V _{OH1} (Note 1)	2 3		11,12,13 11,12,13				9,10 9,10	8 8
	VOH2	7	5	4					8
Logic '0' Output Voltage	VOL1 (Note 1)	2 3		11,12,13 11,12,13				9,10 9,10	8 8
	V _{OL2}	7	4	5					8
Logic '1' Threshold Voltage	VOHA (Note 2)	2 3			11,12,13 11,12,13				8 8
Logic '0' Threshold Voltage	V _{OLA} (Note 3)	2 3				11,12,13 11,12,13			8 8
Short Circuit Current	los	7	5	4				7	8

ELECTRICAL CHARACTERISTICS (continued) (Supply Voltage = 5.0 V, unless otherwise noted.)

NOTES: 1. Test outputs of the device must be tested by sequencing through the truth table. All input, power supply and ground voltages must be maintained between tests. The clock input is the waveform shown. 2. In addition to meeting the output levels specified, the device must divide by 5 or 8 during this test. The clock

input is the waveform shown.

Clock Input VIHmax VILmin

3. In addition to meeting the output levels specified, the device must divide by 6 or 9 during this test. The clock input is the waveform shown.

				TEST V	OLTAGE/Cl	JRRENT VA	LUES		
				Volts			mA		1
	@ Test Temp	perature	VIHT	VILT	Vcc	١L	IOL	Іон	1
		–30°C	2.0	0.8	5.0	-0.25	16	-0.40	1
		25°C	2.0	0.8	5.0	-0.25	16	-0.40	1
		85°C	2.0	0.8	5.0	-0.25	16	-0.40	1
		Pin	TE	ST VOLTAGE		TO PINS LIS	STED BEL	ow	1
Characteristic	Symbol	Under Test	VIHT	VILT	V _{CC}	١L	IOL	ЮН	(V _{EE} Gnd
Power Supply Drain Current	ICC1	8			1,16				8
	I _{CC2}	6			6				8
Input Current	linH1	15 11 12 13	9,10 9,10 9,10		1,16 1,16 1,16 1,16 1,16				8 8 8 8
	linH2	4 5			6 6				8 8
	l _{inH3}	5			6				8
	linH4	9 10			1,16 1,16				8 8
Leakage Current	linL1	15 11 12 13			1,16 1,16 1,16 1,16 1,16				8,15 8,11 8,12 8,13
	linL2	9 10			1,16 1,16				8 8
Reference Voltage	V _{BB}	14			1,16	14			8
Logic '1' Output Voltage	VOH1 (Note 1)	2 3			1,16 1,16				8 8
	V _{OH2}	7			6			7	8
Logic '0' Output Voltage	VOL1 (Note 1)	2 3			1,16 1,16				8 8
	V _{OL2}	7			6		7		8
Logic '1' Threshold Voltage	VOHA (Note 2)	2 3	9,10 9,10		1,16 1,16				8 8
Logic '0' Threshold Voltage	V _{OLA} (Note 3)	2 3		9,10 9,10	1,16 1,16				8 8
Short Circuit Current	los	7			6			1	8

ELECTRICAL CHARACTERISTICS (continued) (Supply Voltage = 5.0 V, unless otherwise noted.)

NOTES: 1. Test outputs of the device must be tested by sequencing through the truth table. All input, power supply and

ground voltages must be maintained between tests. The clock input is the waveform shown. 2. In addition to meeting the output levels specified, the device must divide by 5 or 8 during this test. The clock input is the waveform shown. Clock Input

VIHmax

VILmin

3. In addition to meeting the output levels specified, the device must divide by 6 or 9 during this test. The clock input is the waveform shown.

SWITCHING CHARACTERISTICS

		Pin		ML12509, ML12511, ML12513								TEST VOLTAGES/WAVEFORMS APPLIED TO PINS LISTED E						BELOW:		
		Under		–30°C			25°C			85°C			Pulse	Pulse	Pulse	VIHmin	VILmin	VF	VEE	Vcc
Characteristic	Symbol	Test	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit	Gen.1	Gen.2	Gen.3	†	†	-3.0 V	-3.0 V	+2.0
Propagation Delay (See Figures 3 and 5)	t _{15+ 2+} t _{15+ 2-} t _{5+ 7+} t _{5- 7-}	2 2 7 7	- - -		8.1 7.5 8.4 6.5			8.1 7.5 8.1 6.5			8.9 8 2 8.9 7.1	ns 	15 15 A A	 	 		11,12,13 11,12,13 — —	9,10 9,10 —	8 8 8	1,6,16 1,6,16 1,6,16 1,6,16
Setup Time (See Figures 4 and 5)	t _{setup1} t _{setup2}	11 9	5.0 5.0	_	_	5.0 5.0	_	_	5.0 5.0	_	_	ns ns	15 15	* _	-	=	* 11,12,13	9,10 *	8 8	1,6,16 1,6,16
Release Time (See Figures 4 and 5)	t _{rel1} t _{rel2}	11 9	5.0 5.0	_	_	5.0 5.0	_	_	5.0 5.0	_	_	ns ns	15 15	* _	•	_	* 11,12,13	9.10 *	8 8	1,6,16 1,6,16
Toggle Frequency (See Figure 6) ML12509 : 5/6 ML12511 : 8/9	f _{max}	2	440 500	_	_	480 550			440 500			MHz				11 11			8 8	16 16

*Test inputs sequentially, with Pulse Generator 2 or 3 as indicated connected to input under test, and the voltage indicated applied to the other input(s) of the same type (i.e., MECL or MTTL).

	-30°C	25°C	85°C	
†V _{IHmin}	1.03	1.115	1.20	Vdc
†V _{ILmin}	0.175	0.200	0.235	Vdc

Figure 3. AC Voltage Waveforms

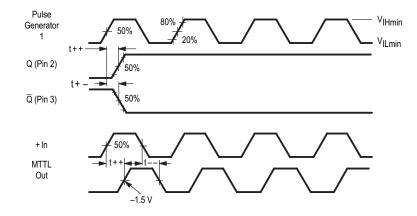
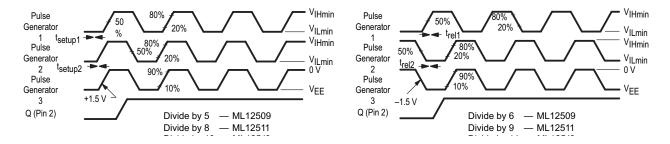


Figure 4. Setup and Release Time Waveforms



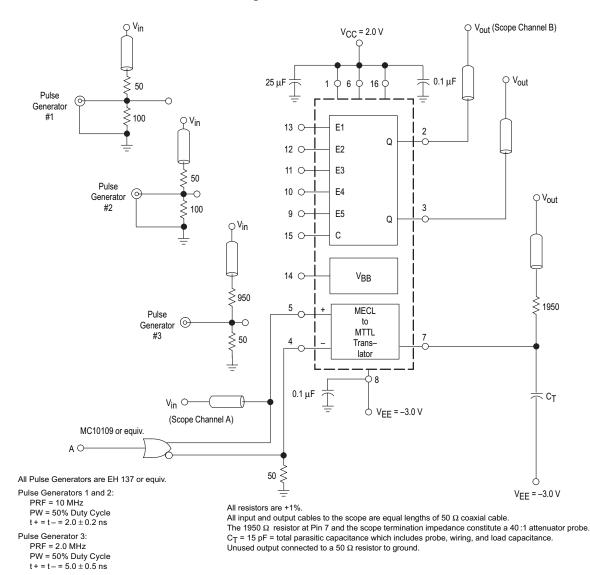


Figure 5. AC Test Circuit

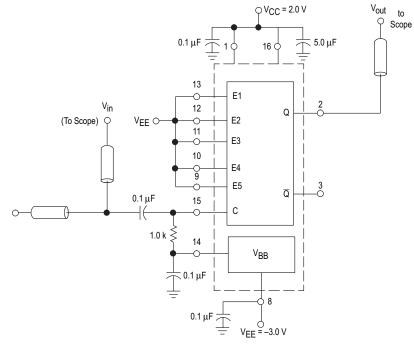
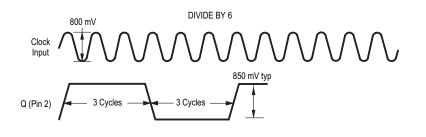


Figure 6. Maximum Frequency Test Circuit

Unused output connected to a 50 Ω resistor to ground



DIVIDE BY 9

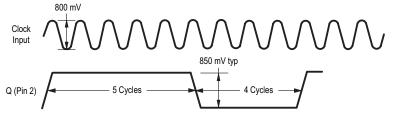
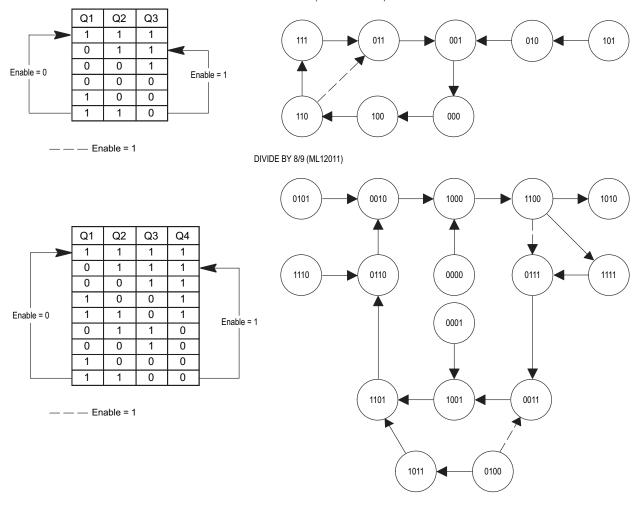


Figure 7. State Diagram

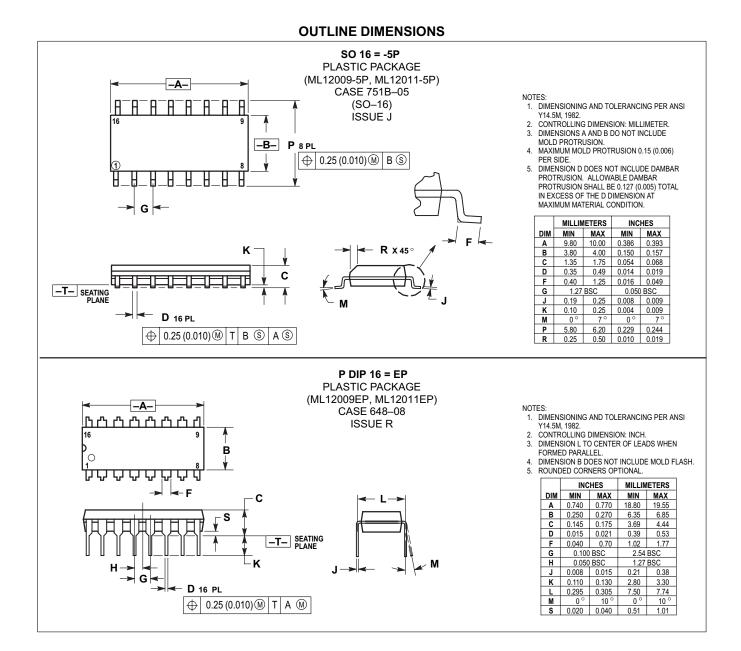
DIVIDE BY 5/6 (ML12009/ML12509)



APPLICATIONS INFORMATION

The primary application of these devices is as a high–speed variable modulus prescaler in the divide by N section of a phase–locked loop synthesizer used as the local oscillator of two–way radios.

Proper VHF termination techniques should be followed when the clock is separated from the prescaler by any appreciable distance. In their basic form, these devices will divide by 5/6 or 8/9. Division by 5, or 8 occurs when any one or all of the five gate inputs E1 through E5 are high. Division by 6, or 9 occurs when all inputs E1 through E5 are low. (Unconnected MTTL inputs are normally high, unconnected MECL inputs are normally low). With the addition of extra parts, many different division configurations may be obtained.



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